

## Silicon PIN Photodiode



### FEATURES

- Package type: surface mount
- Package form: top view
- Dimensions (L x W x H in mm): 5 x 4.24 x 1.12
- Radiant sensitive area (in mm<sup>2</sup>): 7.7
- AEC-Q101 qualified
- Enhanced blue photo sensitivity: S (400 nm) rel > 30 %
- Peak sensitivity at 940 nm
- Suitable for visible and near infrared radiation
- Low junction capacitance
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 65^\circ$
- Floor life: 72 h, MSL 4, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

### DESCRIPTION

TEMD5080X01 is a PIN photodiode with enhanced blue sensitivity. The miniature surface mount package (SMD) include a chip with 7.7 mm<sup>2</sup> sensitive area, covered by clear epoxy.

### Note

\*\* Please see document "Vishay Material Category Policy": [www.vishay.com/doc?99902](http://www.vishay.com/doc?99902)

### APPLICATIONS

- High speed photo detector

| PRODUCT SUMMARY |                      |         |                       |
|-----------------|----------------------|---------|-----------------------|
| COMPONENT       | I <sub>ra</sub> (μA) | φ (deg) | λ <sub>0.1</sub> (nm) |
| TEMD5080X01     | 60                   | ± 65    | 350 to 1100           |

### Note

- Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION |               |                              |              |
|----------------------|---------------|------------------------------|--------------|
| ORDERING CODE        | PACKAGING     | REMARKS                      | PACKAGE FORM |
| TEMD5080X01          | Tape and reel | MOQ: 1500 pcs, 1500 pcs/reel | Top view     |

### Note

- MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                   |                   |               |      |
|---|-----------------------------------|-------------------|---------------|------|
| PARAMETER   | TEST CONDITION                    | SYMBOL            | VALUE         | UNIT |
| Reverse voltage   |                                   | V <sub>R</sub>    | 25            | V    |
| Power dissipation   | T <sub>amb</sub> ≤ 25 °C          | P <sub>V</sub>    | 215           | mW   |
| Junction temperature  |                                   | T <sub>j</sub>    | 100           | °C   |
| Operating temperature range   |                                   | T <sub>amb</sub>  | - 40 to + 100 | °C   |
| Storage temperature range   |                                   | T <sub>stg</sub>  | - 40 to + 110 | °C   |
| Soldering temperature   | Acc. reflow solder profile fig. 8 | T <sub>sd</sub>   | 260           | °C   |
| Thermal resistance junction/ambient   |                                   | R <sub>thJA</sub> | 350           | K/W  |



| BASIC CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                              |      |                         |      |       |
|--|--|------------------------------|------|-------------------------|------|-------|
| PARAMETER  | TEST CONDITION   | SYMBOL                       | MIN. | TYP.                    | MAX. | UNIT  |
| Forward voltage  | I <sub>F</sub> = 50 mA   | V <sub>F</sub>               |      | 1                       | 1.3  | V     |
| Breakdown voltage  | I <sub>R</sub> = 100 μA, E = 0   | V <sub>(BR)</sub>            | 25   |                         |      | V     |
| Reverse dark current   | V <sub>R</sub> = 10 V, E = 0   | I <sub>ro</sub>              |      | 2                       | 10   | nA    |
| Diode capacitance  | V <sub>R</sub> = 0 V, f = 1 MHz, E = 0                                   | C <sub>D</sub>               |      | 90                      |      | pF    |
|  | V <sub>R</sub> = 3 V, f = 1 MHz, E = 0                                   | C <sub>D</sub>               |      | 30                      | 40   | pF    |
| Open circuit voltage   | E <sub>e</sub> = 1 mW/cm <sup>2</sup> , λ = 950 nm                       | V <sub>o</sub>               |      | 350                     |      | mV    |
| Temperature coefficient of V <sub>o</sub>                                    | E <sub>e</sub> = 1 mW/cm <sup>2</sup> , λ = 950 nm                       | TK <sub>V<sub>o</sub></sub>  |      | - 2.6                   |      | mV/K  |
| Short circuit current  | E <sub>e</sub> = 1 mW/cm <sup>2</sup> , λ = 950 nm                       | I <sub>k</sub>               |      | 50                      |      | μA    |
| Temperature coefficient of I <sub>k</sub>                                    | E <sub>e</sub> = 1 mW/cm <sup>2</sup> , λ = 950 nm                       | TK <sub>I<sub>k</sub></sub>  |      | 0.1                     |      | %/K   |
| Reverse light current  | E <sub>e</sub> = 1 mW/cm <sup>2</sup> , λ = 400 nm, V <sub>R</sub> = 5 V | I <sub>ra</sub>              |      | 18                      |      | μA    |
|  | E <sub>v</sub> = 100 lx, CIE illuminant A, V <sub>R</sub> = 5 V          | I <sub>ra</sub>              |      | 8.5                     |      | μA    |
|  | E <sub>e</sub> = 1 mW/cm <sup>2</sup> , λ = 950 nm, V <sub>R</sub> = 5 V | I <sub>ra</sub>              |      | 60                      |      | μA    |
| Temperature coefficient of I <sub>ra</sub>                                   | CIE illuminant A   | TK <sub>I<sub>ra</sub></sub> |      | 0.15                    |      | %/K   |
|  | λ = 950 nm   | TK <sub>I<sub>ra</sub></sub> |      | 0.1                     |      | %/K   |
| Angle of half sensitivity  |  | φ                            |      | ± 65                    |      | deg   |
| Wavelength of peak sensitivity   |  | λ <sub>p</sub>               |      | 940                     |      | nm    |
| Range of spectral bandwidth  |  | λ <sub>0.1</sub>             |      | 350 to 1100             |      | nm    |
| Noise equivalent power   | V <sub>R</sub> = 10 V, λ = 400 nm  | NEP                          |      | 1.1 x 10 <sup>-13</sup> |      | W/√Hz |
| Rise time  | V <sub>R</sub> = 5 V, R <sub>L</sub> = 50 Ω, λ = 850 nm                  | t <sub>r</sub>               |      | 40                      |      | ns    |
| Fall time  | V <sub>R</sub> = 5 V, R <sub>L</sub> = 50 Ω, λ = 850 nm                  | t <sub>f</sub>               |      | 40                      |      | ns    |

**BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

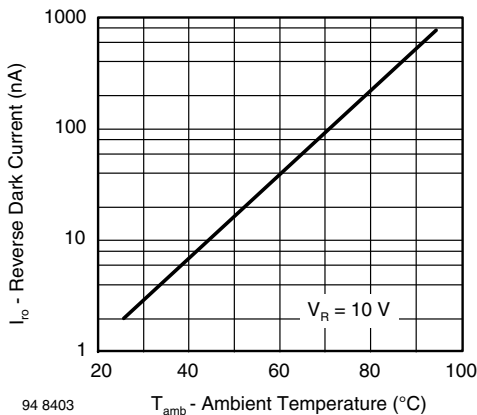


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

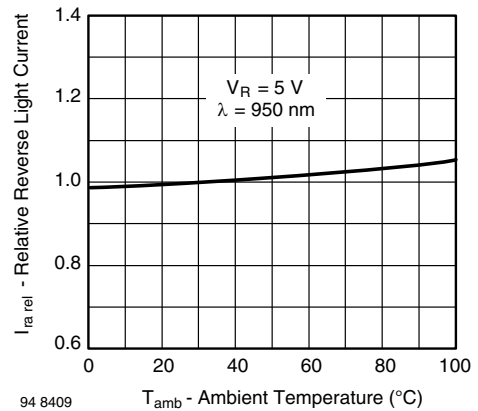


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

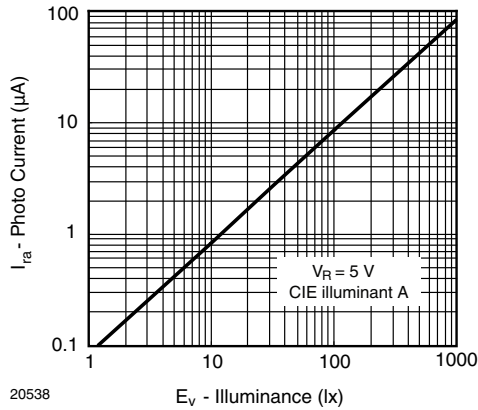


Fig. 3 - Reverse Light Current vs. Irradiance

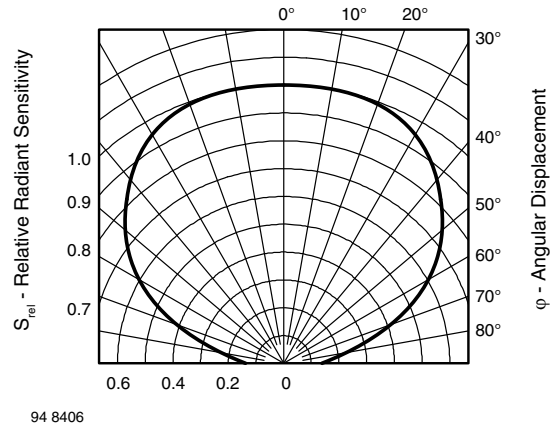


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

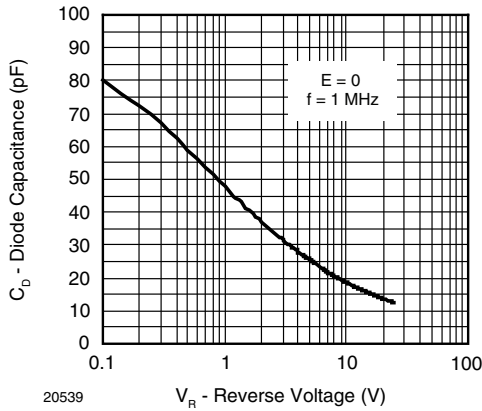


Fig. 4 - Diode Capacitance vs. Reverse Voltage

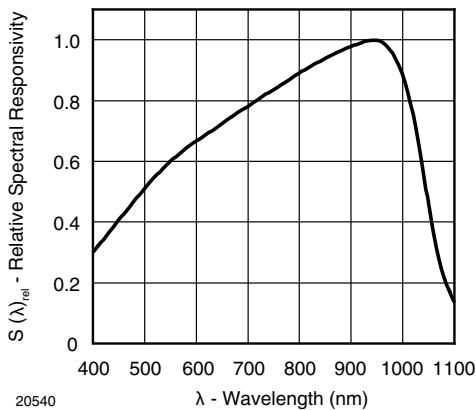
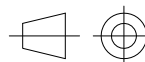
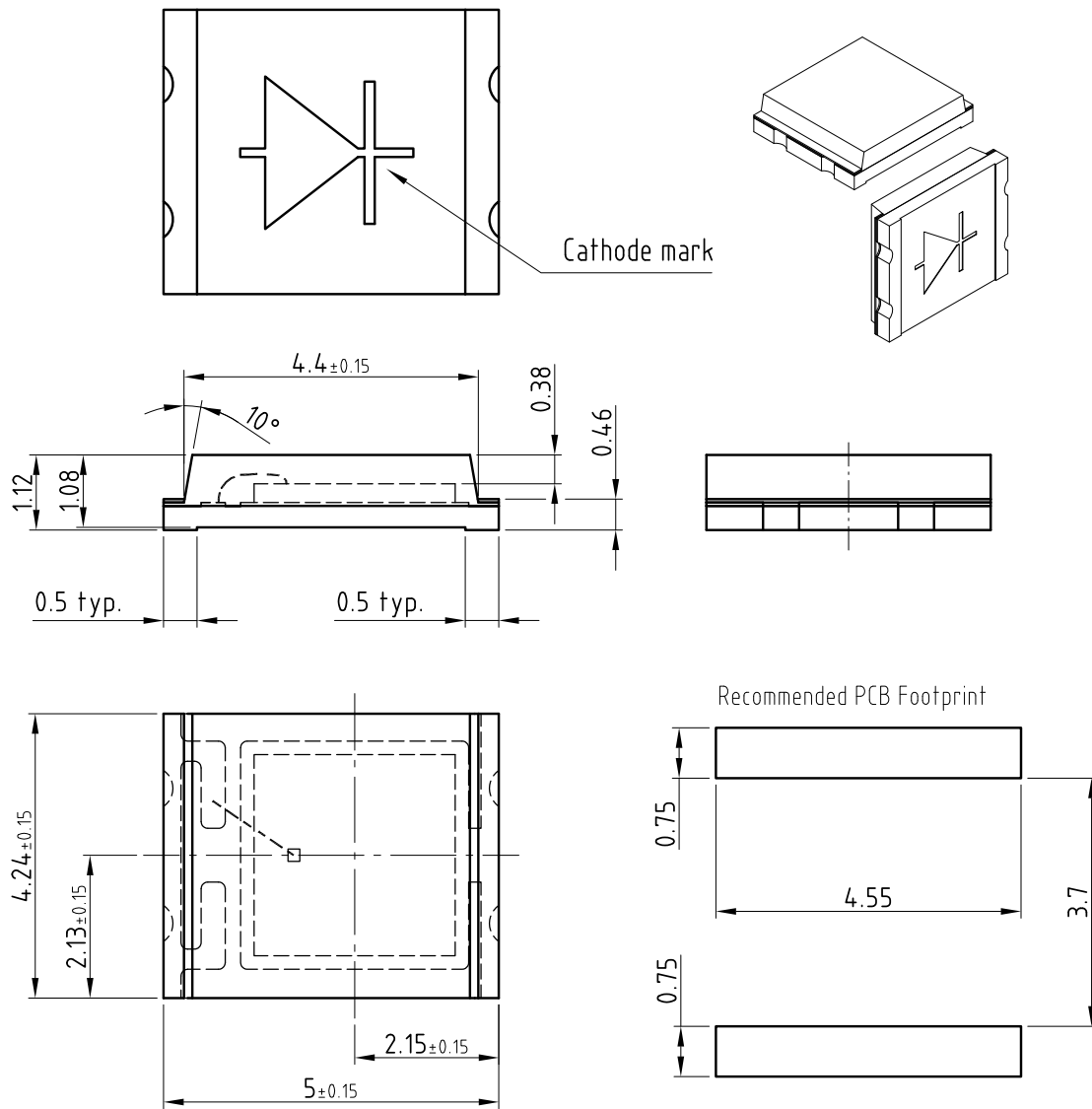


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength



### PACKAGE DIMENSIONS in millimeters



Technical drawings according to DIN specifications

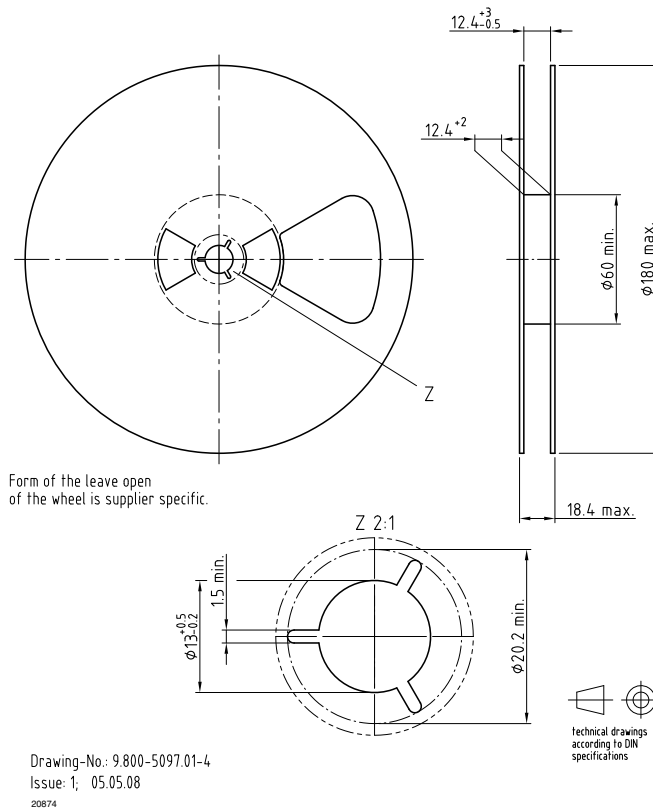
Drawing-No.: 6.541-5060.01-4  
Issue: 3; 05.02.08  
20536

Not indicated tolerances  $\pm 0.1$

**TAPING DIMENSIONS** in millimeters



**REEL DIMENSIONS** in millimeters





**SOLDER PROFILE**

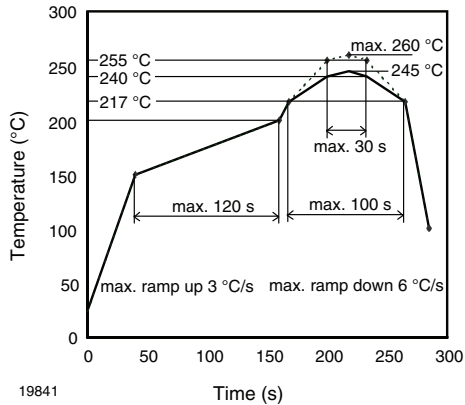


Fig. 7 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020D

**DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

**FLOOR LIFE**

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 4

Floor life: 72 h

Conditions:  $T_{amb} < 30\text{ }^{\circ}\text{C}$ , RH < 60 %

**DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at 40 °C (+ 5 °C), RH < 5 %

or

96 h at 60 °C (+ 5 °C), RH < 5 %.



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